

L Number	Hits	Search Text	DB	Time stamp
-	22	(US-6611002-\$ or US-6593191-\$ or US-5877070-\$ or US-6530991-\$ or US-6464780-\$ or US-6563118-\$).did. or (US-20020074552-\$ or US-20030011000-\$ or US-20030132433-\$ or US-20030102490-\$ or US-20020060317-\$).did. or (US-20020074552-\$ or DE-19802977-\$ or US-20030011000-\$).did.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/06 10:41
-	14	((US-6611002-\$ or US-6593191-\$ or US-5877070-\$ or US-6530991-\$ or US-6464780-\$ or US-6563118-\$).did. or (US-20020074552-\$ or US-20030011000-\$ or US-20030132433-\$ or US-20030102490-\$ or US-20020060317-\$).did. or (US-20020074552-\$ or DE-19802977-\$ or US-20030011000-\$).did.) and (GaN or AlGaN or (gallium near2 nitride\$1))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/06 10:51
-	1	GaN/SiGe	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/06 10:44
-	1	SiGe/GaN	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/06 10:44
-	50	SiGe near3 GaN	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/06 10:47
-	1521	(257/190-192).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/06 10:50
-	8418	(257/79-103).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/06 10:50
-	1576	(257/13-19).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/06 10:50
-	10816	((257/190-192).ccls.) or ((257/79-103).ccls.) or ((257/13-19).ccls.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/06 10:51
-	1298	((257/190-192).ccls.) or ((257/79-103).ccls.) or ((257/13-19).ccls.) and (GaN or AlGaN or (gallium near2 nitride\$1))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/06 10:51
-	159	((257/190-192).ccls.) or ((257/79-103).ccls.) or ((257/13-19).ccls.) and (GaN or AlGaN or (gallium near2 nitride\$1)) and (SiGe or "SixGe(1-x)" or "Si.sub.x Ge.sub.(1-x)" or (silicon near germanium))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/06 11:43

-	114	("3670213" "4398342" "4482422" "4772929" "4845044" "4984043" "5055445" "5140651" "5194397" "5227196" "5281834" "5326721" "5394489" "5441577" "5473047" "5492859" "5504183" "5515810" "5549977" "5596205" "5650646" "5674366" "5754319" "5792679" "5825055" "5833603" "5874860" "5912068" "5987011" "6022140" "6049702" "6103008" "6153454" "6184044" "6224669" "6248459" "6291319" "6316785" "2001/0013313").PN.	"4242595" "4424589" "4748485" "4773063" "4882300" "4999842" "5073981" "5155658" "5204870" "5248564" "5310707" "5352926" "5406202" "5453727" "5486406" "5494711" "5511238" "5528057" "5552547" "5602418" "5656382" "5679965" "5777350" "5801072" "5827755" "5863326" "5883564" "5948161" "6002375" "6023082" "6055179" "6108125" "6175497" "6191011" "6239449" "6252261" "6139483" "6316832"	"4289920" "4459325" "4756007" "4841775" "4901133" "5051790" "5081519" "5185589" "5225031" "5270298" "5314547" "5356509" "5418389" "5466631" "5491461" "5504035" "5515047" "5528067" "5572052" "5610744" "5659180" "5731220" "5789845" "5801105" "5828080" "5872493" "5907792" "5959879" "6011646" "6028853" "6078717" "6153010" "6175555" "6204737" "6241821" "6255198" "6313486" "6343171"	USPAT	2003/11/06 11:38
-	279	(GaN or AlGaN or (gallium near2 nitride\$1)) with (SiGe or "SixGe(1-x)" or "Si.sub.x Ge.sub.(1-x)" or (silicon near germanium))			USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/17 11:54
-	57	Watanabe near Daisuke			USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/06 11:44
-	2	(Watanabe near Daisuke) and (GaN or AlGaN or (gallium near2 nitride\$1))			USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/06 11:46
-	4	"2003023011"			USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/06 11:46
-	0	"2003JP-023011"			USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/06 11:46
-	0	2003JP-023011\$3			USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/06 11:47

-	0	2003JP023011\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/06 11:47
-	1	JP2003023011\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/06 11:48
-	2	2001-204216	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/06 11:48
-	2	"2001204216"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/06 11:49
-	2	JP2001204216\$2	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/06 11:49
-	17	(GaN or AlGaN or (gallium near2 nitride\$1)) and ((SiGe or "SixGe(1-x)" or "Si.sub.x Ge.sub.(1-x)" or (silicon near germanium)) near3 (buffer or graded or intermediate))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/06 12:47
-	2	"20030102490"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/06 12:08
-	9	("Re33693" "4861393" "4994866" "5019882" "5155571" "5442205" "5461243" "5683934" "5705421").PN.	USPAT	2003/11/06 12:41
-	1	((monocrystal\$6 or crystal\$6) near5 (GaN or AlGaN or (gallium near2 nitride\$1))) and ((SiGe or "SixGe(1-x)" or "Si.sub.x Ge.sub.(1-x)" or (silicon near germanium)) near3 (buffer or graded or intermediate))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/06 12:49
-	113	((monocrystal\$6 or crystal\$6) near5 (GaN or AlGaN or (gallium near2 nitride\$1))) and ((SiGe or "SixGe(1-x)" or "Si.sub.x Ge.sub.(1-x)" or (silicon near germanium)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/06 12:49
-	0	"2003JP-023011" and ((SiGe or "SixGe(1-x)" or "Si.sub.x Ge.sub.(1-x)" or (silicon near germanium)) with substrate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/06 12:51
-	0	"2003JP-023011" and ((silicon near germanium) with substrate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/06 12:51
-	0	"2003JP-023011" and ((silicon near\$4 germanium) with substrate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/06 12:51

-	39	((monocrystal\$6 or crystal\$6) near5 (GaN or AlGaN or (gallium near2 nitride\$1))) and ((SiGe or "SixGe(1-x)" or "Si.sub.x Ge.sub.(1-x)" or (silicon near germanium))) and ((SiGe or "SixGe(1-x)" or "Si.sub.x Ge.sub.(1-x)" or (silicon near germanium)) with substrate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/06 12:52
-	7	(GaN or AlGaN or (gallium near2 nitride\$1)) with (crack near2 level)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/06 14:19
-	4	"2003023011"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/17 11:21
-	2	(Watanabe near Daisuke) and ((gallium near2 nitride) or GaN)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/17 11:23
-	2	(TANABE near MITSURU) and ((gallium near2 nitride) or GaN)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/17 11:23
-	59	(Watanabe near Daisuke)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/17 11:32
-	119	shouxiang near hu	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/17 11:33
-	2	"6589335"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/17 11:44
-	16	("4863877" "5091767" "5134446" "5221413" "5408487" "5621227" "5659187" "5728623" "5751753" "6010937" "6030884" "6039803" "6057560" "6191006" "6252221" "6392257").PN.	USPAT	2003/11/17 11:44
-	0	6589335.URPN.	USPAT	2003/11/17 11:51
-	44	(GaN or AlGaN or (gallium near2 nitride\$1)) with buffer with (thermal near expan\$6)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/17 14:22
-	104	(GaN or AlGaN or (gallium near2 nitride\$1)) with silicon with germanium with substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/17 14:33
-	48	((GaN or AlGaN or (gallium near2 nitride\$1)) with silicon with germanium with substrate) and epitax\$5	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/17 14:33
-	11	((GaN or AlGaN or (gallium near2 nitride\$1)) near2 substrate) same (SiGe or "SixGe(1-x)" or "Si.sub.x Ge.sub.(1-x)" or (silicon near germanium))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/17 16:26

-	1	WO98/44569	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/17 16:27
-	0	WO9844569	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/17 16:27
-	2	WO adj "9844569"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/17 16:27